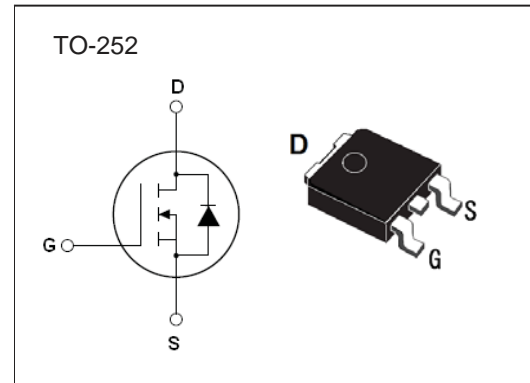


N-Channel MOSFET

2KK5053

■ Features

- $V_{DS} (V) = 250 V$
- $I_D = 18 A$
- $R_{DS(ON)}$ (at $V_{GS} = 10 V$) $< 230 m\Omega$
- Low gate charge
- Low C_{rss} (typical 12.2pF)
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

■ Absolute Maximum Ratings ($T_C = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	250	V
Gate-Source Voltage	V_{GS}	± 30	
Continuous Drain Current (Note 1)	I_D	$T_C = 25^\circ C$	18
		$T_C = 100^\circ C$	10.97
Pulsed Drain Current (Note 1)	I_{DM}	72	A
Single Pulse Avalanche Energy (Note 2)	E_{AS}	607.5	mJ
Avalanche Current (Note 1)	I_{AR}	18	A
Repetitive Avalanche Current (Note 1)	E_{AR}	3.21	mJ
Peak Diode Recovery dv/dt (Note 3)	dv/dt	4.3	V/ns
Power Dissipation	P_D	120	W
Thermal Resistance, Junction- to-Case	$R_{\theta JC}$	1.04	$^\circ C/W$
Thermal Resistance, Junction- to-Ambient	$R_{\theta JA}$	110	
Junction Temperature	T_J	150	$^\circ C$
Storage Temperature Range	T_{stg}	-55 to 150	

Notes:

1. Drain current limited by maximum junction temperature
2. $L=3mH$, $I_{AS}=18A$, $V_{DD}=50V$, $R_G=25 \Omega$, Starting $T_J=25^\circ C$
3. $I_{SD} \leq 40A$, $di/dt \leq 300A/\mu s$, $V_{DD} \leq BV_{DSS}$, Starting $T_J=25^\circ C$

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■ Electrical Characteristics ($T_c = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$I_D = 250 \mu\text{A}$, $V_{GS} = 0\text{V}$	250			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 250\text{V}$, $V_{GS} = 0\text{V}$			1	μA
		$V_{DS} = 200\text{V}$, $V_{GS} = 0\text{V}$, $T_J = 125^\circ\text{C}$			10	
Gate to Source Leakage Current	I_{GSS}	$V_{DS} = 0\text{V}$, $V_{GS} = \pm 30\text{V}$			± 100	nA
On Characteristics						
Gate to Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250\mu\text{A}$	2		4	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS} = 10\text{V}$, $I_D = 9\text{A}$		160	230	m Ω
Forward Transconductance (Note 4)	g_{FS}	$V_{DS} = 40\text{V}$, $I_D = 18\text{A}$		9.7		S
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{GS} = 0\text{V}$, $V_{DS} = 25\text{V}$, $f = 1\text{MHz}$		703.4	1150	pF
Output Capacitance	C_{oss}			178.8	285	
Reverse Transfer Capacitance	C_{rss}			12.2	21.4	
Switching Characteristics						
Total Gate Charge	Q_g	$V_{GS} = 10\text{V}$, $V_{DS} = 200\text{V}$, $I_D = 18\text{A}$ (Note 4,5)		17.5	25.4	nC
Gate Source Charge	Q_{gs}			4.08		
Gate Drain Charge	Q_{gd}			9.12		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS} = 10\text{V}$, $V_{DD} = 125\text{V}$, $I_D = 18\text{A}$, $R_G = 25\Omega$ (Note 4,5)		8	22	ns
Turn-On Rise Time	t_r			46	93.5	
Turn-Off Delay Time	$t_{d(off)}$			39	76.1	
Turn-Off Fall Time	t_f			37.4	69.1	
Drain-Source Diode Characteristics						
Body Diode Reverse Recovery Time	t_{rr}	$I_F = 18\text{A}$, $di/dt = 100\text{A}/\mu\text{s}$, $V_{GS} = 0\text{V}$ (Note 4)		157		ns
Body Diode Reverse Recovery Charge	Q_{rr}			0.89		nC
Diode Forward Voltage	V_{SD}	$V_{GS} = 0\text{V}$, $I_S = 18\text{A}$			1.4	V

Notes:

- Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2\%$
- Essentially independent of operating temperature

■ Marking

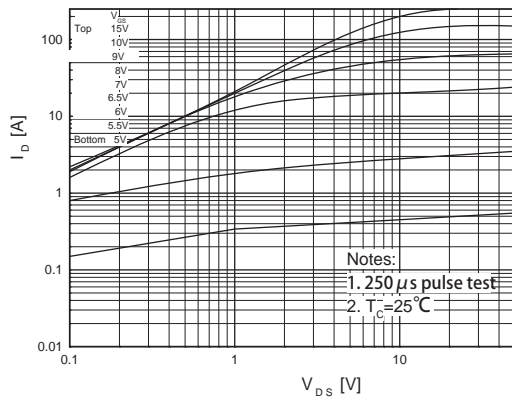
Marking	K5053
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N-Channel MOSFET

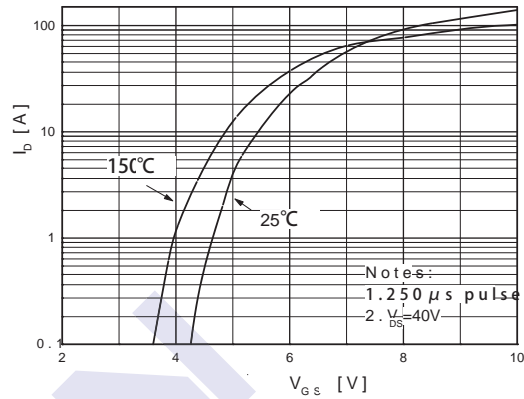
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Typical Characteristics

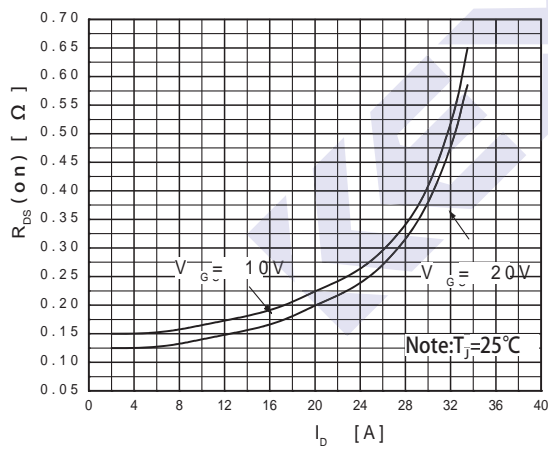
On-Region Characteristics



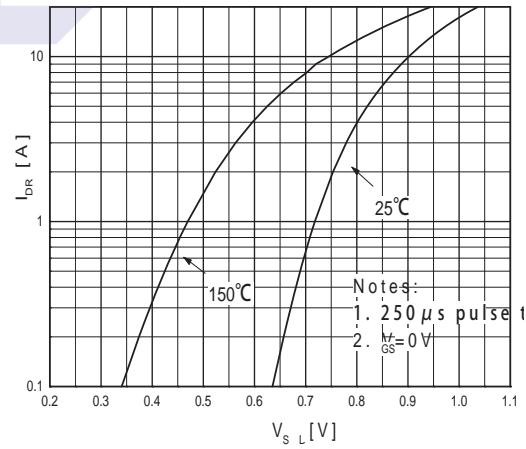
Transfer Characteristics



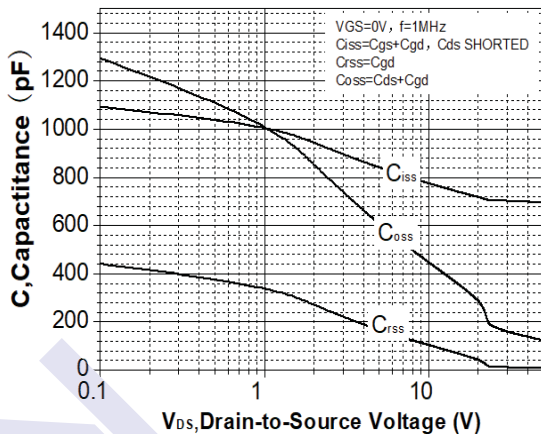
On-Resistance Variation vs. Drain Current and Gate Voltage



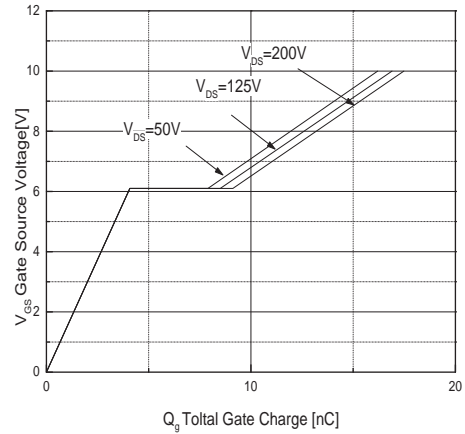
Body Diode Forward Voltage Variation vs. Source Current and Temperature



Capacitance Characteristics

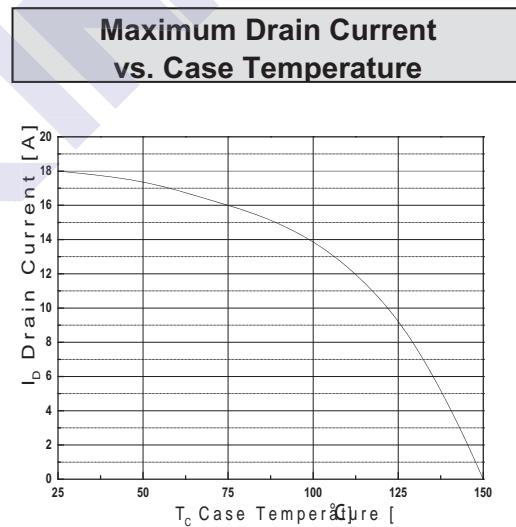
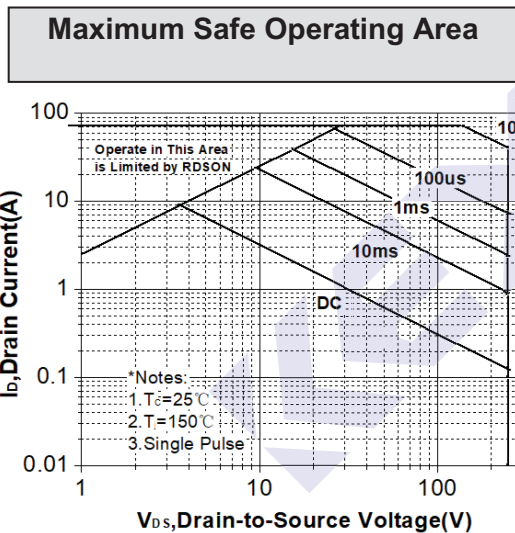
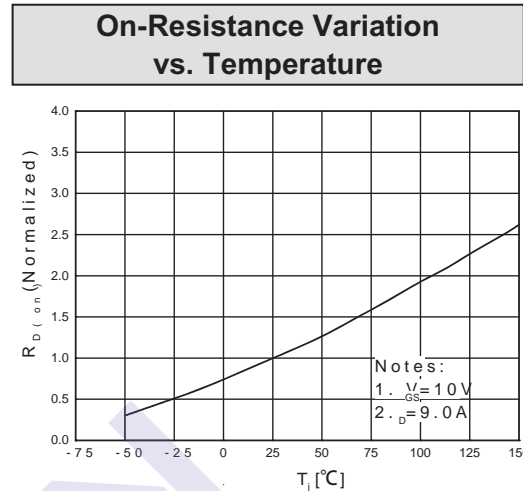
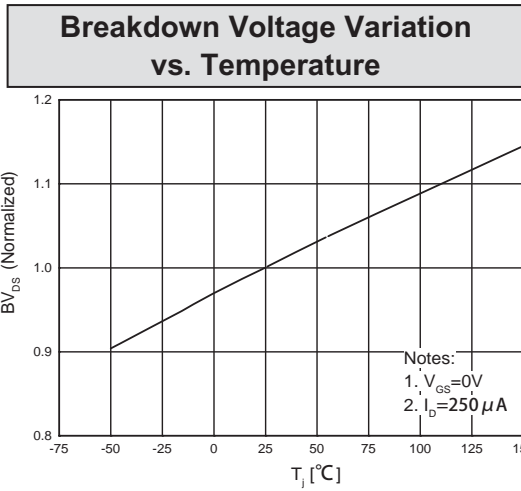


Gate Charge Characteristics

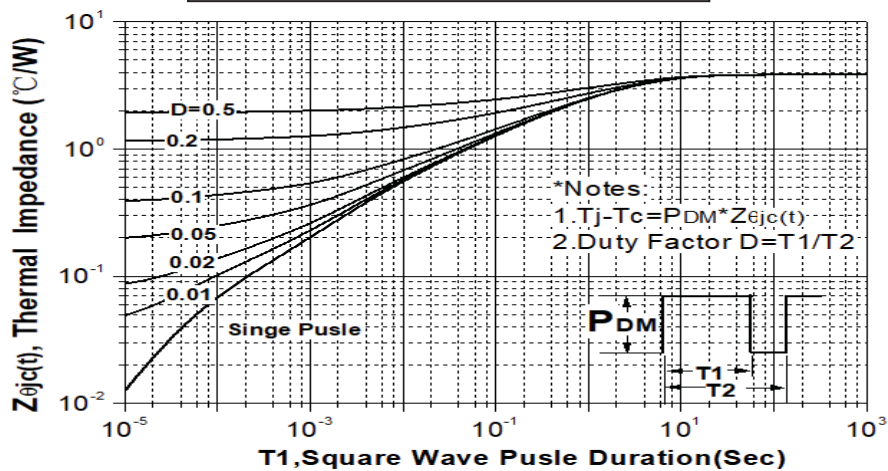


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Transient Thermal Response Curve

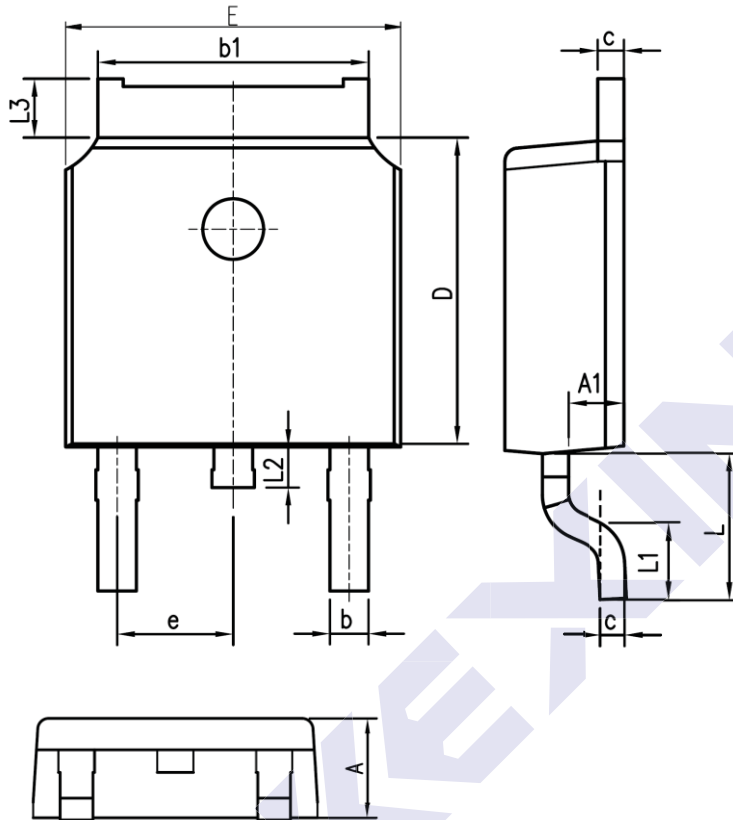


N-Channel MOSFET

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■ Package Outline Dimensions

Unit:mm



SYMBOL	mm	
	MIN	MAX
A	2.10	2.50
A1	0.97	1.17
b	0.63	0.93
b1	5.13	5.53
c	0.40	0.60
D	5.80	6.40
E	6.30	6.90
e	2.286BSC	
L	2.50	3.30
L1	1.20	1.80
L2	0.60	1.00
L3	0.85	1.30